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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











### 74AHCT138

#### 3 TO 8 LINE DECODER DEMULTIPLEXER

## **Description**

The 74AHCT138 is an advanced high speed CMOS device that is designed to be pin compatable with 74LS low power Schottky types.

The device accepts a three bit binary weighted address on input pins A0, A1 and A2 and when enabled will produce one active low output with the remaining seven being high.

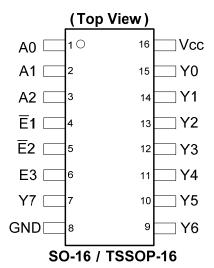
There are two active LOW enable inputs  $\overline{E}1$  and  $\overline{E}2$ , and one active HIGH enable input E3. The disabled device state results in all outputs being high. The enable state occurs with  $\overline{E}1$  and  $\overline{E}2$  asserted low and E3 asserted high.

The multiple enable lines allow for the parallel expansion of decoders to create 4-to-16 line versions with no additional parts and 5-to-32 versions with the addition of a single inverter.

#### **Features**

- Supply Voltage Range from 4.5V to 5.5V
- Sinks or Sources 8mA at V<sub>CC</sub> = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- Inputs Accept up to 6.0V
- ESD Protection Tested per JESD 22
- Exceeds 200-V Machine Model (A115-A)
- Exceeds 2000-V Human Body Model (A114-A)
- Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Pin Assignments**



### **Applications**

- Memory chip select decoding
- Demultiplexing
- Single line peripheral control
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet

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# **Pin Descriptions**

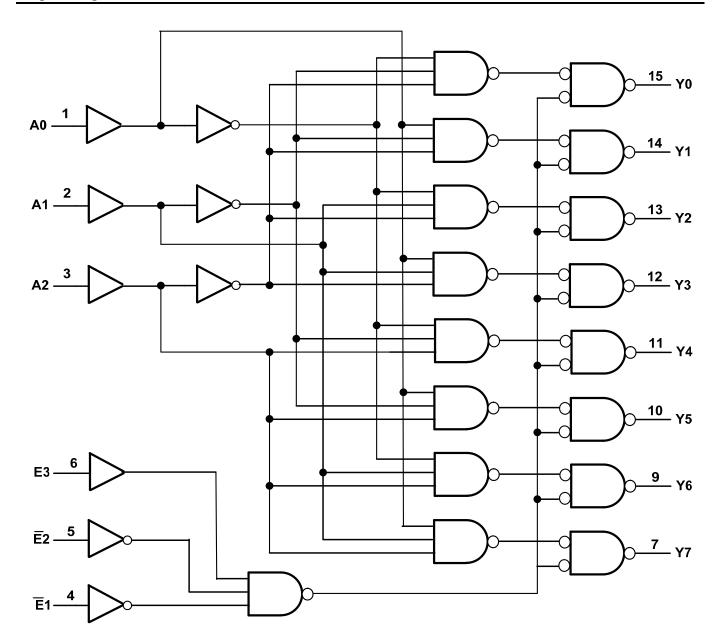
Pin Number	Pin Name	Description
1	A0	Address Input 0
2	A1	Address Input 1
3	A2	Address Input 2
4	<u>=</u> 1	Enable Input 1 (active LOW)
5	E <sub>2</sub>	Enable Input 2 (active LOW)
6	E3	Enable Input 3 (active HIGH)
7	Y7	Output 7 (active LOW)
8	GND	Ground
9	Y6	Output 6 (active LOW)
10	Y5	Output 5 (active LOW)
11	Y4	Output 4 (active LOW)
12	Y3	Output 3 (active LOW)
13	Y2	Output 2 (active LOW)
14	Y1	Output 1 (active LOW)
15	Y0	Output o (active LOW)
16	V <sub>C</sub> C	Supply Voltage

# **Function Table Diagram**

	Control			Input					(	Output			
E <sub>1</sub>	E2	E3	A2	<b>A</b> 1	A0	<del>Y</del> 7	<u>₹</u> 6	<del>Y</del> 5	<b>∀</b> 4	<del>7</del> 3	<u>¥</u> 2	<u>Y</u> 1	<u>₹</u> 0
Н	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Х	Н	Х											
Х	Х	L											
L	L	Н											
			L	L	L	Н	Н	Н	Н	Н	Н	Н	L
			L	L	Н	Н	Н	Н	Н	Н	Н	L	Н
			L	Н	L	Н	Н	Н	Н	Н	L	Н	Н
			L	Н	Н	Н	Н	Н	Н	L	Н	Н	Н
			Н	L	L	Н	Н	Н	L	Н	Н	Н	Н
			Н	L	Н	Н	Н	L	Н	Н	Н	Н	Н
			Н	Н	L	Н	L	Н	Н	Н	Н	Н	Н
			Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н



# **Logic Diagram**





# Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
Vo	Voltage applied to output in high or low state	-0.3 to V <sub>CC</sub> +0.5	V
lıĸ	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
lok	Output Clamp Current Vo<-0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub> + 0.5V	25	mA
I <sub>O</sub>	Continuous output current	+/- 25	mA
Icc	Continuous current through V <sub>DD</sub> or GND	75	mA
I <sub>GND</sub>	Continuous current through V <sub>DD</sub> or GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Notes:

# Recommended Operating Conditions (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		4.5	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	Active Mode	0	V <sub>CC</sub>	V
Δt/ΔV	Input transition Rise or Fall Rate	V <sub>CC</sub> = 4.5V to 5.5V		20	ns/V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+125	°C

Note:

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Cymbol	Parameter	Test Conditions	V	TA	= +25°(	2	T <sub>A</sub> = -40°C	to +85°C	T <sub>A</sub> = -40°C	to +125°C	Unit
Symbol	Cymbol Farameter	rest Conditions	V <sub>CC</sub>	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-level Input Voltage		4.5V to 5.5V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	Low-level input voltage		4.5V to 5.5V	-	-	0.8	-	0.8	-	0.8	V
	High Level	I <sub>OH</sub> = -50μA	4.5V	4.4	4.5	-	4.4	-	4.4	-	V
$V_{OH}$	Output Voltage	I <sub>OH</sub> = -8mA	4.5V	3.94	_	_	3.80	-	3.70	-	V
.,	Low-level Output	I <sub>OL</sub> = 50μA	4.5V	_	0	0.1	-	0.1	-	0.1	V
VoL	Voltage	I <sub>OL</sub> = 8mA	4.5V	-	-	0.36	-	0.44	-	0.55	V
II	Input Current	V <sub>I</sub> = GND or 5.5V	0V to 5.5V	_	0.1	±0.1	-	± 1	-	± 2	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	5.5V	-	-	4.0	-	40	-	80	μΑ
Δl <sub>CC</sub>	Additional Supply Current per Input	V <sub>I</sub> = Vcc -2.1V I <sub>O</sub> = 0	4.5V to 5.5V	ĺ	=	1.35	-	1.5	_	1.5	mA
C <sub>i</sub>	Input Capacitance	$V_i = V_{CC}$ or GND	5.5V	-	4	10	-	10	-	10	pF

<sup>4.</sup> Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

<sup>5.</sup> Unused inputs should be held at  $V_{\text{CC}}$  or Ground.



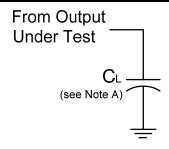
# **Switching Characteristics**

Symbol	Parameter	Test Conditions	V	T <sub>A</sub> = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
Syllibol	Parameter	rest Conditions	V <sub>CC</sub>	Min	Тур	Max	Min	Max	Min	Max	Onn
	Propagation Delay	Figure 2 C <sub>L</sub> =15pF	4.5V to 5.5V	0.5	4.4	10.4	1.0	12.0	1.0	13.0	20
	An to $\overline{Y}$ n	Figure 2 C <sub>L</sub> = 50pF	4.5V to 5.5V	0.5	6.2	11.4	1.0	13.0	1.0	14.5	ns
	Propagation Delay	Figure 2 C <sub>L</sub> = 15pF	4.5V to 5.5V	0.5	4.3	9.1	1.0	10.5	1.0	11.5	20
t <sub>PD</sub>	E3 to $\overline{Y}$ n	Figure 2 C <sub>L</sub> = 50pF	4.5V to 5.5V	0.5	6.2	10.1	1.0	11.5	1.0	13.0	ns
	Propagation Delay	Figure 2 C <sub>L</sub> = 15pF	4.5V to 5.5V	0.5	4.3	9.6	1.0	11.0	1.0	12.0	no
	En to Yn	Figure 2 C <sub>L</sub> = 50pF	4.5V to 5.5V	0.5	6.2	10.6	1.0	12.0	1.0	13.5	ns

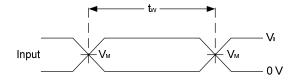
# Operating Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V <sub>CC</sub> = 5V Typ	Unit
$C_{\sf pd}$	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	23	pF

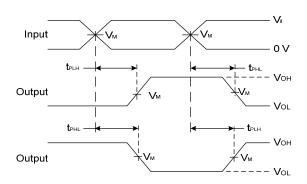
#### **Parameter Measurement Information**



V	Inp	outs	V	м	
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	Input	Output	OL.
4.5V to 5.5V	3.0 V	3ns	1.5 V	V <sub>CC</sub> /2	15pF, 50pF



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

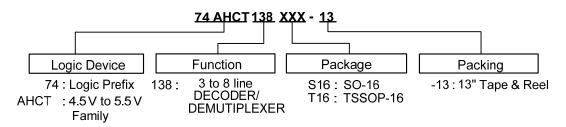
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate  $\leq$  10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .



Figure 1. Load Circuit and Voltage Waveforms

# **Ordering Information**

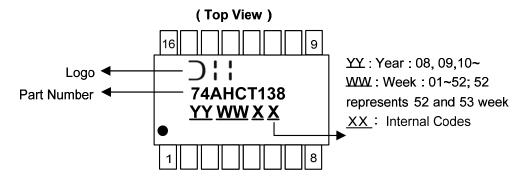


Dort Number	Dookses Code	Dookoaina	7" Tape an	d Reel (Note 7)
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHCT138S16-13	S16	SO-16	2500/Tape & Reel	-13
74AHCT138T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Notes: 7. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

### **Marking Information**

#### (1) SO-16, TSSOP16



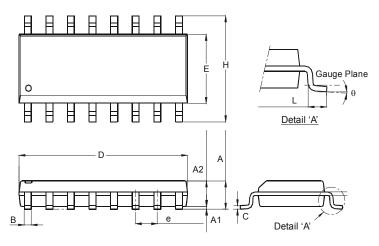
Part Number	Package
74AHCT138S16	SO-16
74AHCT138T16	TSSOP-16



# Package Outline Dimensions (All dimensions in mm.)

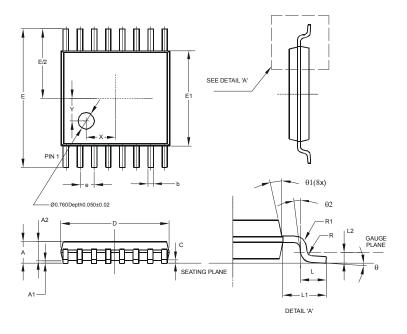
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-16



	SO-16	
Dim	Min	Max
Α	1.40	1.75
A1	0.10	0.25
A2	1.30	1.50
В	0.33	0.51
C	0.19	0.25
D	9.80	10.00
Е	3.80	4.00
е	1.27	Тур
Н	5.80	6.20
٦	0.38	1.27
Θ	0°	8°
All D	imension	s in mm

## Package Type: TSSOP-16



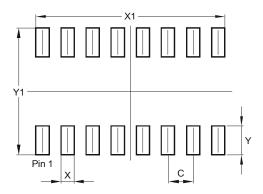
TSSOP-16							
Dim	Min	Max	Тур				
Α	-	1.08	-				
<b>A</b> 1	0.05	0.15	-				
A2	0.80	0.93	-				
b	0.19	0.30	-				
С	0.09	0.20	-				
D	4.90	5.10	-				
П	6	.40 BS	SC				
E1	4.30	4.50	-				
Ф	0	.65 BS	SC				
Г	0.45	0.75	-				
L1	1	.00 R	EF				
L2	0	.25 BS	SC SC				
R	0.09	-	-				
R1	0.09	ı	-				
X	-	-	1.350				
Υ	-	-	1.050				
Θ	0°	8°	-				
Θ1	5°	15°	-				
Θ2	0°	-	-				
All Dimensions in mm							



# **Suggested Pad Layout**

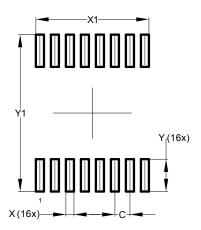
 $Please see AP02001 \ at \ http://www.diodes.com/datasheets/ap02001.pdf \ for \ the \ latest \ version.$ 

#### Package Type: SO-16



Dimensions	Value (in mm)
С	1.270
Х	0.670
X1	9.560
Υ	1.450
Y1	6.400

### Package Type: TSSOP-16



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	4.900
Υ	1.400
Y1	6 800



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